

#### HALF-BRIDGE DRIVER

#### **Features**

- Floating channel designed for bootstrap operation
- Fully operational to +600 V
- Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 10 V to 20 V
- Undervoltage lockout
- 3.3 V, 5 V, and 15 V logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- Internal set deadtime
- High side output in phase with HIN input
- Low side output out of phase with LIN input

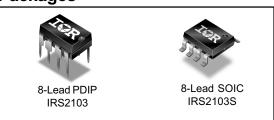
#### **Description**

The IRS2103 is a high voltage, high speed power MOSFET and IGBT drivers with dependent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable rugge-dized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down

#### **Product Summary**

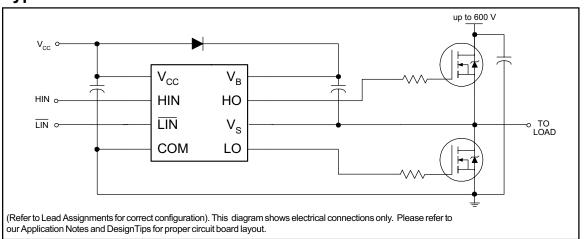
Voffset	600 V max.
I <sub>O</sub> +/-	130 mA/270 mA
Vout	10 V - 20 V
t <sub>on/off</sub> (typ.)	680 ns/150 ns
Deadtime (typ.)	520 ns

#### **Packages**



to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 V.

#### **Typical Connection**



#### **Absolute Maximum Ratings**

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units	
V <sub>B</sub>	High side floating absolute voltage		-0.3	625	
Vs	High side floating supply offset voltage		V <sub>B</sub> - 25	V <sub>B</sub> + 0.3	
V <sub>HO</sub>	High side floating output voltage		V <sub>S</sub> - 0.3	V <sub>B</sub> + 0.3	
V <sub>CC</sub>	Low side and logic fixed supply voltage		-0.3	25	, v
V <sub>LO</sub>	Low side output voltage		-0.3	V <sub>CC</sub> + 0.3	
V <sub>IN</sub>	Logic input voltage (HIN & LIN)	-0.3	V <sub>CC</sub> + 0.3		
dV <sub>S</sub> /dt	Allowable offset supply voltage transient		_	50	V/ns
D.	Package power dissipation @ T <sub>A</sub> ≤ +25 °C (8 Lead PDIP) (8 Lead SOIC)		_	1.0	w
P <sub>D</sub>			_	0.625	, vv
Dth	Rth <sub>JA</sub> Thermal resistance, junction to ambient (8 Lead PDIP) (8 Lead SOIC)		_	125	90/14/
Kuija			_	200	°C/W
TJ	Junction temperature		_	150	
T <sub>S</sub>	Storage temperature		-55	150	°C
TL	Lead temperature (soldering, 10 seconds)		_	300	

#### **Recommended Operating Conditions**

The input/output logic timing diagram is shown in Fig. 1. For proper operation the device should be used within the recommended conditions. The  $V_S$  offset rating is tested with all supplies biased at a 15 V differential.

Symbol	Definition	Min.	Max.	Units
V <sub>B</sub>	High side floating supply absolute voltage	V <sub>S</sub> + 10	V <sub>S</sub> + 20	
Vs	High side floating supply offset voltage	Note 1	600	
V <sub>HO</sub>	High side floating output voltage	Vs	V <sub>B</sub>	.,
Vcc	Low side and logic fixed supply voltage	10	20	V
V <sub>LO</sub>	Low side output voltage	0	V <sub>CC</sub>	
V <sub>IN</sub>	Logic input voltage (HIN & LIN)	0	V <sub>CC</sub>	
T <sub>A</sub>	Ambient temperature	-40	125	°C

Note 1: Logic operational for  $V_S$  of -5 V to +600 V. Logic state held for  $V_S$  of -5 V to -V<sub>BS</sub>. (Please refer to the Design Tip DT97-3 for more details).

#### **Dynamic Electrical Characteristics**

 $V_{BIAS}$  (V<sub>CC</sub>, V<sub>BS</sub>) = 15 V, C<sub>L</sub> = 1000 pF and T<sub>A</sub> = 25 °C unless otherwise specified.

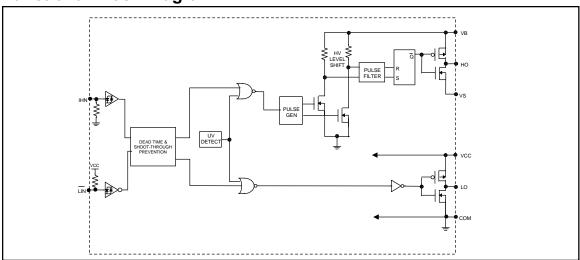
Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
ton	Turn-on propagation delay	_	680	820		V <sub>S</sub> = 0 V
toff	Turn-off propagation delay	_	150	220		V <sub>S</sub> = 600 V
t <sub>r</sub>	Turn-on rise time	_	70	170		
tf	Turn-off fall time	_	35	90	ns	
DT	Deadtime, LS turn-off to HS turn-on &	400	520	650		
D1	HS turn-on to LS turn-off	100	020			
MT	Delay matching, HS & LS turn-on/off	_	_	60		

#### **Static Electrical Characteristics**

 $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 15 V and  $T_A$  = 25 °C unless otherwise specified. The  $V_{IN}$ ,  $V_{TH}$ , and  $I_{IN}$  parameters are referenced to COM. The  $V_O$  and  $I_O$  parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Symbol	Definition	Min.	Тур.	Max.	Units	<b>Test Conditions</b>
VIH	Logic "1" (HIN) & Logic "0" (LIN) input voltage	2.5	_	_		V== 40.V+= 20.V
V <sub>IL</sub>	Logic "0" (HIN) & Logic "1" (LIN) input voltage	_	_	0.8	V	V <sub>CC</sub> = 10 V to 20 V
VoH	High level output voltage, V <sub>BIAS</sub> - V <sub>O</sub>	_	0.05	0.2	v	I <sub>O</sub> = 2 mA
V <sub>OL</sub>	Low level output voltage, VO	_	0.02	0.1		10 - 2 11// (
I <sub>LK</sub>	Offset supply leakage current	_	l	50		$V_{B} = V_{S} = 600 \text{ V}$
I <sub>QBS</sub>	Quiescent V <sub>BS</sub> supply current	_	30	55		
lacc	Quiescent V <sub>CC</sub> supply current	_	150	270	μΑ	$V_{IN} = 0 \text{ V or 5 V}$
I <sub>IN+</sub>	Logic "1" input bias current	_	3	10		$HIN = 5 \text{ V}, \overline{LIN} = 0 \text{ V}$
I <sub>IN-</sub>	Logic "0" input bias current	_	_	1		$HIN = 0 \text{ V}, \overline{LIN} = 5 \text{ V}$
Vccuv+	V <sub>CC</sub> supply undervoltage positive going threshold	8	8.9	9.8	V	
V <sub>CCUV</sub> -	V <sub>CC</sub> supply undervoltage negative going threshold	7.4	8.2	9	V	
I <sub>O+</sub>	Output high short circuit pulsed current	130	290		- mA	$V_O = 0 \text{ V}, V_{IN} = V_{IH}$ $PW \le 10  \mu\text{s}$
I <sub>O-</sub>	Output low short circuit pulsed current	270	600	_	, IIIA	$V_O = 15 \text{ V}, V_{IN} = V_{IL}$ $PW \le 10  \mu\text{s}$

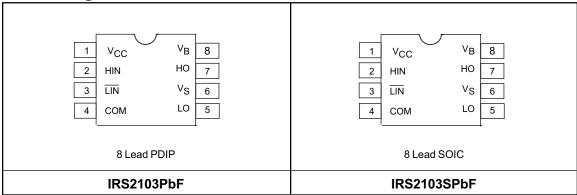
### **Functional Block Diagram**



#### **Lead Definitions**

Symbol	Description
HIN	Logic input for high side gate driver output (HO), in phase
LIN	Logic input for low side gate driver output (LO), out of phase
VB	High side floating supply
НО	High side gate drive output
Vs	High side floating supply return
Vcc	Low side and logic fixed supply
LO	Low side gate drive output
COM	Low side return

### **Lead Assignments**



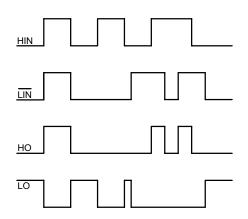
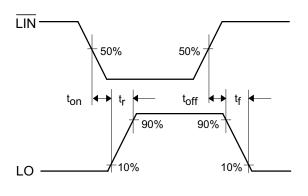


Figure 1. Input/Output Timing Diagram



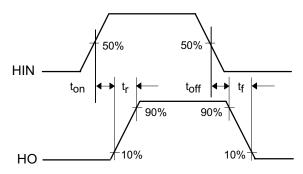


Figure 2. Switching Time Waveform Definitions

HIN 50% 50%

HO DT 10%

LO 90%

Figure 3. Deadtime Waveform Definitions

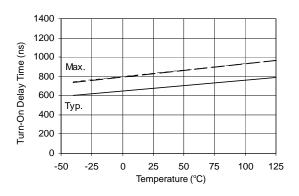


Figure 4A. Turn-On Time vs. Temperature

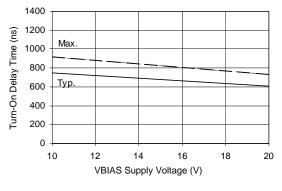


Figure 4B. Turn-On Time vs. Supply Voltage

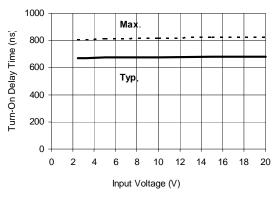


Figure 4C. Turn-On Time vs. Input Voltage

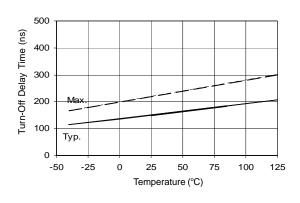


Figure 5A. Turn-Off Time vs. Temperature

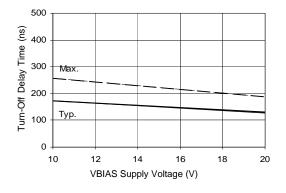


Figure 5B. Turn-Off Time vs. Supply Voltage

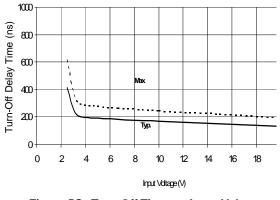


Figure 5C. Turn-Off Time vs. Input Voltage

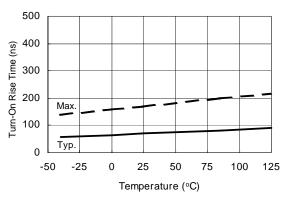


Figure 6A. Turn-On Rise Time vs. Temperature

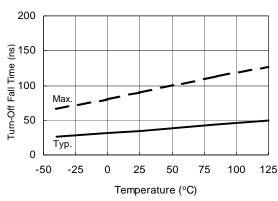


Figure 7A. Turn-Off Fall Time vs. Temperature

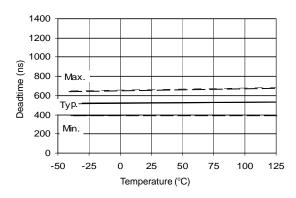


Figure 8A. Deadtime vs. Temperature

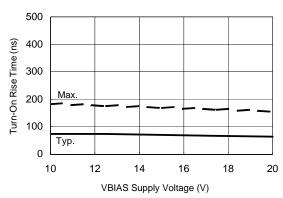


Figure 6B. Turn-On Rise Time vs. Voltage

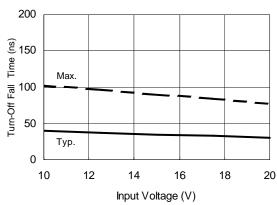


Figure 7B. Turn-Off Fall Time vs. Voltage

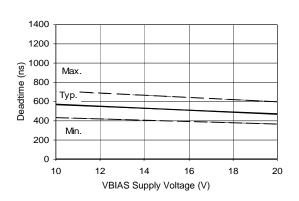


Figure 8B. Deadtime vs. Voltage

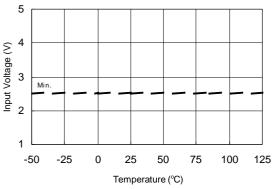


Figure 9A. Logic "1" Input Voltage vs. Temperature

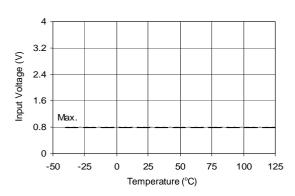


Figure 10A. Logic "0"(HIN) & Logic "1" (LIN) Input Voltage vs. Temperature

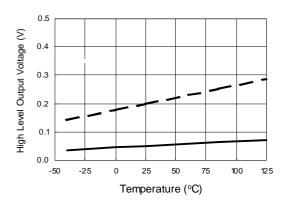


Figure 11A. High Level Output Voltage vs. Temperature

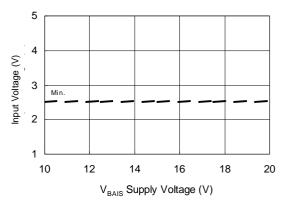


Figure 9B. Logic "1" Input Voltage vs. Supply Voltage

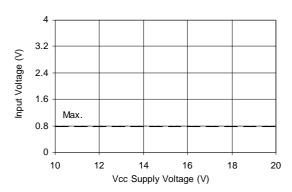


Figure 10B. Logic "0"(HIN) & Logic "1" (LIN) Input Voltage vs. Voltage

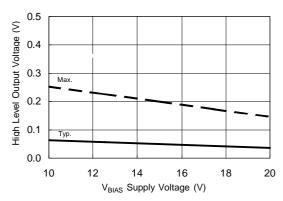


Figure 11B. High Level Output Voltage vs. Supply Voltage

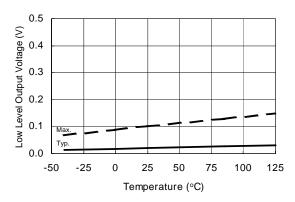
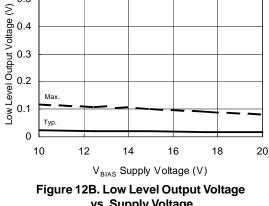


Figure 12A. Low Level Output Voltage vs. Temperature



0.5

vs. Supply Voltage

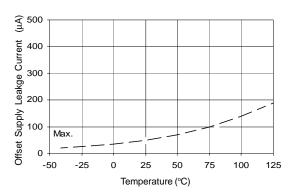


Figure 13A. Offset Supply Current vs. Temperature

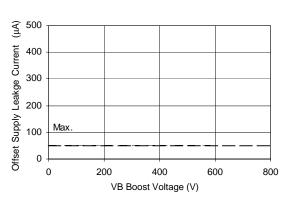


Figure 13B. Offset Supply Current vs. Voltage

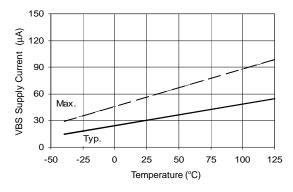


Figure 14A. V<sub>BS</sub> Supply Current vs. Temperature

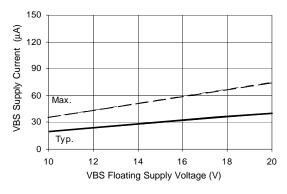
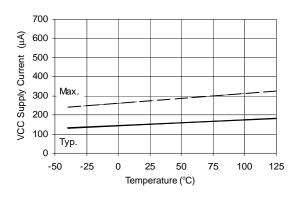


Figure 14B. V<sub>BS</sub> Supply Current vs. Voltage

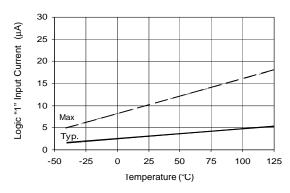


VCC Supply Current (µA) 600 500 400 300 Max. 200 100 Тур. 0 12 16 18 20 10 14 Vcc Supply Voltage (V)

700

Figure 15A. Vcc Supply Current vs. Temperature

Figure 15B. Vcc Supply Current vs. Voltage



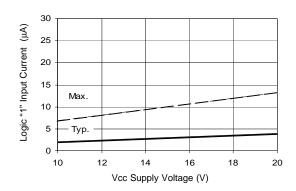
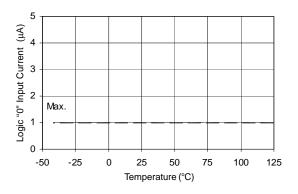


Figure 16A. Logic "1" Input Current vs. Temperature

Figure 16B. Logic "1" Input Current vs. Voltage



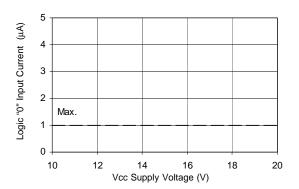
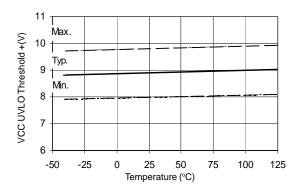


Figure 17A. Logic "0" Input Current vs. Temperature

Figure 17B. Logic "0" Input Current vs. Voltage

## International TOR Rectifier

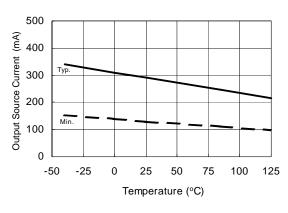
### IRS2103(S)PbF



11 VCC UVLO Threshold -(V) 10 Max. 9 Тур. 8 7 Min. 6 -50 -25 0 25 50 75 100 125 Temperature (°C)

Figure 18A. Vcc Undervoltage Threshold(+) vs. Temperature

Figure 18B. Vcc UndervoltageThreshold (-) vs. Temperature



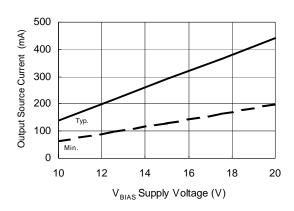
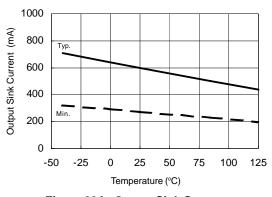


Figure 19A. Output Source Current vs. Temperature

Figure 19B. Output Source Current vs. Supply Voltage



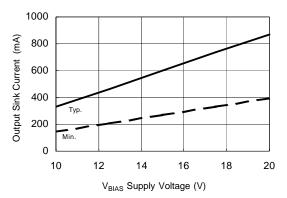
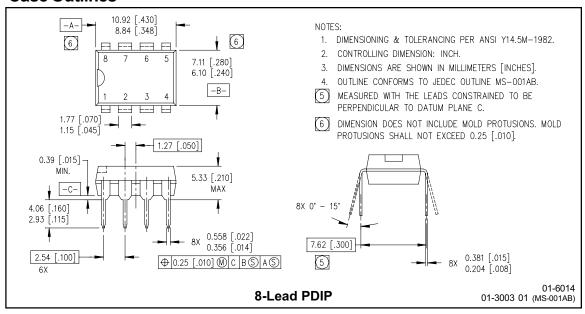


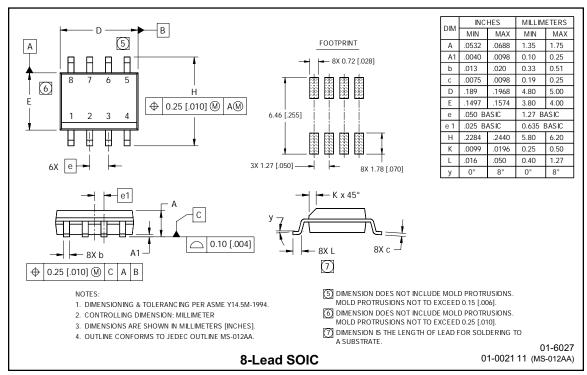
Figure 20A. Output Sink Current vs. Temperature

Figure 20B. Output Sink Current vs. Supply Voltage

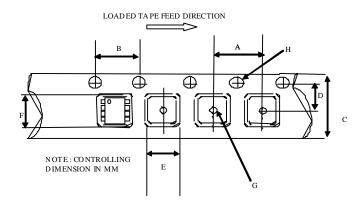
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#### **Case Outlines**



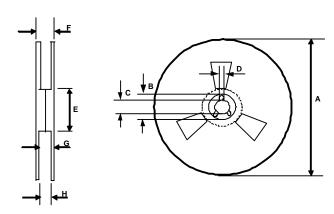


# Tape & Reel 8-lead SOIC



CARRIER TAPE DIMENSION FOR 8SOICN

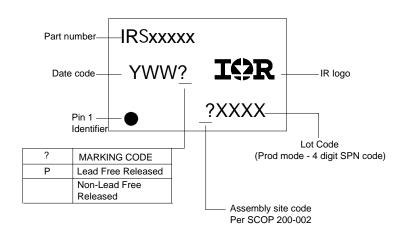
	M e	tric	lm p erial		
Code	Min	Max	Min	Max	
Α	7.90	8.10	0.311	0.318	
В	3.90	4.10	0.153	0.161	
С	11.70	12.30	0.46	0.484	
D	5.45	5.55	0.214	0.218	
E	6.30	6.50	0.248 0.255		
F	5.10	5.30	0.200	0.208	
G	1.50	n/a	0.059	n/a	
Н	1.50	1.60	0.059 0.062		



REEL DIMENSIONS FOR 8SOICN

	M e	tric	Imperial		
Code	Min	Max	Min	Max	
Α	329.60	330.25	12.976	13.001	
В	20.95	21.45	0.824	0.844	
С	12.80	13.20	0.503	0.519	
D	1.95	2.45	0.767	0.096	
E	98.00	102.00	3.858 4.015		
F	n/a	18.40	n/a	0.724	
G	14.50	17.10	0.570	0.673	
Н	12.40	14.40	0.488 0.566		

#### LEADFREE PART MARKING INFORMATION



#### **ORDER INFORMATION**

8-Lead PDIP IRS2103PbF 8-Lead SOIC IRS2103SPbF 8-Lead SOIC Tape & Reel IRS2103STRPbF



The SOIC-8 is MSL2 qualified.

This product has been designed and qualified for the industrial level.

Qualification standards can be found at www.irf.com <a href="http://www.irf.com/">http://www.irf.com/></a>

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245 Tel: (310) 252-7105

Data and specifications subject to change without notice. 6/14/2006